

Obsolete – Part Discontinued



PI3USB223

USB 2.0 High-Speed and Audio Switches with Negative Signal Capability

Features

- → Single +2.7V to +4.4V Supply Voltage
- → Low 50µA Supply Current
- → -3dB Bandwidth: 1500MHz (typ)
- \rightarrow Low 2.5 Ω (typ)On-Resistance
- → THD+N: 0.02%
- \rightarrow Shorting D+/R and D-/L to Vbus will not cause leakage when $V_{DD} = 0$
- → Internal Shunt Resistors for Click-and-Pop Reduction
- → VBUS Detection for Automatic Switch Path Selection
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → Packaging (Pb-free & Green available):
 - 10-pin contact UQFN, 1.4 x 1.8, (ZM10)

Description

The PI3USB223 combines AC coupled audio signals and USB2.0 HS (480Mbps) on the same pins. This enables users to use a single connector to drive either a USB end point or an audio end point.

PI3USB223 incorporates gate pump technology required to maintain low Ron for ideal audio THD while reducing the capacitance affect of high speed USB signals. The device also incorporates a substrate pump technology which allows -2V signals to pass through the switch without causing any leakage.

The PI3USB223 features protection on D+/R and D-/L to ensure no damage will happen to the IC if these pins are shorted accidentally to Vbus as well as ensuring there is no leakage when V_{DD} is on or off. Also, it includes VBUS detection (VB) to automatically switch to the USB signal path upon detection of a valid VBUS signal. It also features internal shunt resistors on the audio path to reduce clicks and pops heard during output. The device is available in a space-saving 10-pin, 1.4mm x 1.8mm UQFN package, and operate over the -40°C to +85°C temperature range.

Block Diagram D+ D+/R D-D-/L R 1 VBUS VVBDET ASEL

Truth Table

ASEL	V _{DD}	VBUS	L/R	D+/D-	L/R Shunt
X	L	L	OFF	OFF	OFF
X	Н	L	OFF	OFF	ON
X	L	Н	OFF	OFF	OFF
L	Н	Н	OFF	ON	ON
Н	Н	Н	ON	OFF	OFF

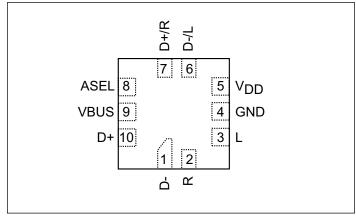
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm
- antimony compounds.





Pin Configuration



Pin Description

Pin#	Name	Description
1	D-	USB D- from system side
2	R	Audio Input (Right)
3	L	Audio Input (Left)
4	GND	Ground
5	V _{DD}	Positive Supply Voltage Input. Bypass V_{DD} to GND with a 0.1 μ F capacitor as close to the device as possible.
6	D-/L	Common Terminal for D- or Left Audio
7	D+/R	Common Terminal for D+ or Right Audio
8	ASEL	Switch SEL to override VBUS detection when VBUS and V_{DD} are both high. If ASEL is HIGH, then audio path will be on If ASEL is LOW then USB path will be on ASEL has an internal 3M-ohm pull-down
9	VBUS	If ASEL is tied LOW, then VBUS detection can be used for auto switching. If ASEL is LOW VBUS = HIGH means USB path is active
10	D+	USB D+ from system side





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

	e ,
(Voltages referenced to GND.)	
V _{DD} , ASEL	-0.3V to +5.0V
V _{BUS}	
$V_{(R/D^+) and} V_{(L/D^-)}^{(1)}$	
$V_{(R/D+)}$ and $V_{(L/D-)}^{(2)}$	-0.3V to +5.0V
V _{R and} V _L	2.0Vto (V _{DD} + 0.3V)
V _{D+ and} V _D	$-0.3V$ to $(V_{DD}+0.3V)$
Continuous Current into Any Terminal	±100mA
Continuous Power Dissipation $(T_A = +70^{\circ}C)10$ -	Pin UQFN
(derate 6.9mW/°C above +70°C)	559mW
Junction-to-Case Thermal Resistance $(\theta JC)^{(2)}$	
10-Pin UQFN	20.1°C/W
Junction-to-Ambient Thermal Resistance (0JA)	(2)
10-Pin UQFN	143.1°C/W
Operating Temperature Range	40°C to +85°C
Junction Temperature Range	40°C to +150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s	+300°C

Notes:

- 1. If Audio path is enabled
- 2. If USB path is enabled

Stresses greater than those listed under MAXIMUM RAT-INGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics

	m 1000	1 .1 .	1		05 0 (C)
$(V_{DD} = 2)/V$ to 4 4V	$T_{\Lambda} = -40^{\circ}C$ to $\pm 85^{\circ}C$	unless otherwise noted	1 Typical values are a	t $V_{DD} = 3.0V$ to 3.6V, T_A	$= 25^{\circ}(2)$
(DD = 0 , 0 , 0 , 0 , 0 , 0 , 0 , 0 , 0 , 0	-A		a. Lyprom (and co are a	$\sim DD$ 2.0 $\sim co$ 2.0 γ A	

Parameter	Symbol		Test Conditions	Min.	Тур.	Max.	Units
Operating Power-supply range	V _{DD}			2.7	_	4.4	V
Supply Current	I _{CC}	$V_{DD} = 3.3 V$	ASEL = VBUS = 0V	_	_	50	μA
Power-supply Rejection Ratio	PSRR		f = 10 kHz, V _{DD} = 3.0 ±0.3V, R _{D+/R} =50Ω	_	60	_	dB
Analog Signal Danga	V _{D+/-}			0		V _{DD}	v
Analog Signal Range	V _{R/L}			-2		V _{DD}	V
R/L On-Resistance	R _{ON(R/L)}		$V_{DD} = 3.0V, V_{R/L} = -1.5V,$ +1.5V, $I_{D+/R}$ and $D_{-/L} = 10mA$		2	5	
			$V_{DD} = 3.0V, V_{D+/-} = -0.4V$ to 0.6V, I _{D+/R and D-/L} = 10mA		3.5	6	
D+/D- On-Resistance	R _{ON(D+/-)}		$V_{DD} = 3.0V,$ $V_{D+/R \text{ and } D-/L} = 0V \text{ to } 3.0V,$ $I_{D+/R \text{ and } D-/L} = 10\text{mA}$			12	Ω
R/L On-Resistance Match between Channels	$\Delta R_{ON(R/L)}$		$V_{DD} = 3.0V, V_{R/L} = 0V, I_{D+/R and}$ D-/L = 10mA			0.2	
D+/- On-Resistance Match between Channels	$\Delta R_{ON(D+/D-)}$		$V_{DD} = 3.0V, V_{D+/-} = 0V,$ $I_{D+/R \text{ and } D-/L} = 10\text{mA}$			0.2	
R/L On-Resistance Flat- ness	R _{FLAT(R/L)}		$V_{DD} = 3.0V, I_{D+/R and D-/L} = 10mA, V_{R/L} = -1.5V to+1.5V$		0.3	0.5	

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Diodes Incorporated





DC Electrical Characteristics Cont.

Parameter	Symbol		Test Conditions	Min.	Тур.	Max.	Units
D+/D- On-Resistance Flatness	R _{FLAT(D+/-)}		$V_{DD} = 3.0V, I_{D+/R and D-/L} = 10m$ A, V _{D+/-} = -0.4V to 0.6V		0.25	0.5	Ω
Shunt Switch Resistance	R _{SH}		Voltage on R or $L = V_{DD}$		25		kΩ
D+/- Off-Leakage Current	I _{D+/-(OFF)}		$V_{DD} = 3.0V, V_{D+/-} = 5V,$ $V_{D+/R \text{ and } D-/L} = -1.5V, +2.5V$	-1		1	
R/L Off-Leakage Current	I _{R/L(OFF)}		$V_{DD} = 3.0V, V_{R/L} = 0V,$ V _ D+/R and D-/L = 0V, +2.5V	-1		1	μA
			$V_{DD} = 3.0V,$ $V_{D+/R \text{ and } D-/L} = 3.6V,$ $V_{D+/-} = V_{R/L} = 0V$			5	μΑ
D+/R and D-/L Off-Leak- age Current	ID+/R and D-/L(OFF)		$V_{DD} = 3.3V,$ $V_{D+/R \text{ and } D-/L} = 0V,$ $V_{D+/-} = V_{R/L} = 0V$			5	
			$V_{DD} = 0V,$ $V_{D+/R \text{ or } D-/L} = 5.0V,$ $V_{D+/-} = V_{R/L} = 0V$			5	
System Bus Input Voltage	V _{BUS}			0		5.5	V
D+/R and D-/L On-Leak- age Current	I _{D+/R} and D-/L(ON)	USB Mode	$V_{DD} = 3.0V,$ $V_{R/L} = 0V,2.5V,$ unconnected, $V_{D+/R \text{ and } D-/L} = 0V, 2.5V$	-200		200	nA
		Audio Mode	$V_{DD} = 3.0V,$ $V_{D+/-} = 0V, 2.5V,$ unconnected, $V_{D+/R \text{ and } D-/L} = -1.5V, +2.5V$	-200		200	
Turn-On Time	t _{ON}	$ \begin{array}{c} \text{R/L to D-/L} \\ \text{or D+/R,} \\ \text{V}_{\text{DD}} = 3.0\text{V,} \\ \text{Fig. 2} \end{array} $	$V_{R/L} = 1.5V, Z_L = 50\text{-ohm}//35\text{pF},$ ASEL = $V_{DD}, V_{BUS} = 5.0V$ to 0V		12	60	
		D+/- to D-/L or D+/R, $V_{DD} = 3.0V$, Fig. 2	$V_{R/L} = 1.5V, Z_L = 50\text{-ohm}//35pF,$ $V_{VBUS} = 5.0V, ASEL = 0V \text{ to } V_{DD}$		12	60	
Turn-Off Time	t _{OFF}	$\begin{array}{c} \text{R/L to D-/L} \\ \text{or D+/R,} \\ \text{V}_{\text{DD}} = 3.0\text{V,} \\ \text{Fig. 2} \end{array}$	$V_{R/L} = 1.5V$, $Z_L = 50$ -ohm//35pF, ASEL = V_{DD} , $V_{BUS} = 5.0V$ to $0V$		1.4	5	μs
		D+/- to D-/L or D+/R, $V_{DD} = 3.0V$, Fig. 2	$V_{R/L} = 1.5V, Z_L = 50\text{-ohm}//35pF,$ $V_{VBUS} = 5.0V, ASEL = 0V \text{ to } V_{DD}$		0.7	5	
Break-Before-Make Time Delay	t _D	$Z_{\rm L} = 50\Omega$ // 3	5pF		13.5		





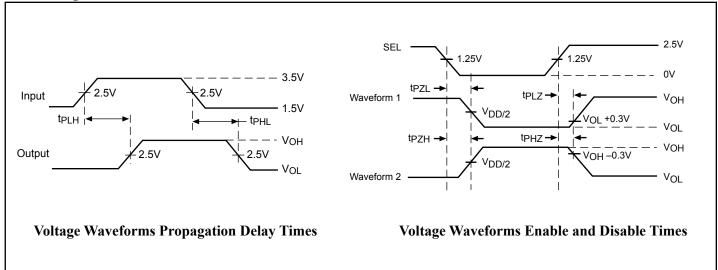
DC Electrical Characteristics Cont.

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Output Skew Same Switch	t _{SK(P)}	Figure 3		10		
Output Skew Between Switches	t _{SK(O)}	Figure 3		10		ps
R/L Off-Capacitance	C _{R/L(OFF)}	$V_{D+/R \text{ and } D-/L} = 0.5 V_{PP}$, DC Bias = 0V, f = 1MHz,		3		
D+/- Off-Capacitance	C _{D+/-(OFF)}	$V_{D+/R \text{ and } D-/L} = 1.5 V_{PP}$, DC Bias = 0V, f = 240MHz,		2.5		pF
On Constitution	C _{D+/R and D-}	USB Path, $F = 240 MHz$, DC bias = 0V		9		
On-Capacitance	/L(ON)	Audio path, $f = 100 \text{kHz}$, DC bias = 0V		8		
AC PERFORMANCE						
R/L -3dB Bandwidth	BW _{R/L}	$R_S = R_L = 50\Omega$, $V_{R/L} = 0$ dBm, Figure 4		1100		MIT
D+/3dB Bandwidth	BW _{D+/-}	$R_S = R_L = 50\Omega$, $V_{D+/-} = 0$ dBm, Figure 4		1500		MHz
Insertion Loss	I _{N((USB Path)}	Frequency = 240MHz		-0.5		- dB
Off Isolation	I _{SO}	Figure 4, $f = 240 MHz$		-35		
Crosstalk	X _{TALK}	$f = 100 \text{kHz}, V_{\text{COM}} = 1 V_{\text{RMS}}, R_{\text{S}} = R_{\text{L}} = 50 \Omega,$ Figure 4		-80		
Total Harmonic Distortion + Noise	THD + N (for audio path)	R/L to D+/R and D-/L, f = 20Hz to 20kHz, $V_{D+/R and D-/L} = 0.5V_{PP}$, DC Bias = 0V, $R_L = 600\Omega$		0.02		%
LOGIC INPUT	I		1	1	,	
Input Logic High	V _{IH} for ASEL		1.6			
Input Logic Low	V _{IL} for ASEL				0.4	
	V _{IH} for Vbus		3.5		5.5	V
	V _{IL} for Vbus		0		0.6	1
Input Leakage Current	I _{IN}	VASEL and VVbus = $0V$ or V_{DD}			10	μΑ
ESD PROTECTION						
All Pins		Human Body Model		±2		
D+/R, D-/L, and VBUS		Human Body Model		±12		kV
D+/R, D-/L, and VBUS		Contact, IEC61000-4-2		±8		





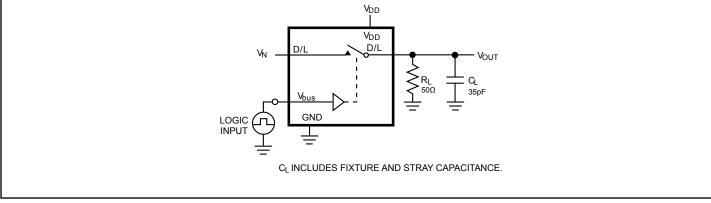
Switching Waveforms







Test Circuits and Timing Diagrams



Note:

Figure 1. AC Test Circuit

1. Unused input (NC or NO) must be grounded.

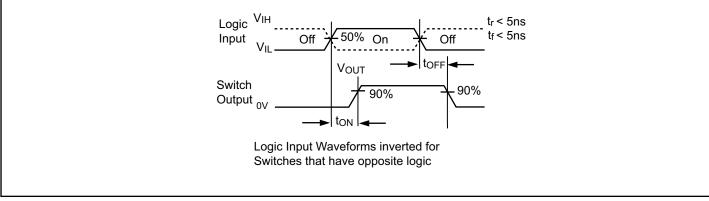


Figure 2. AC Waveforms

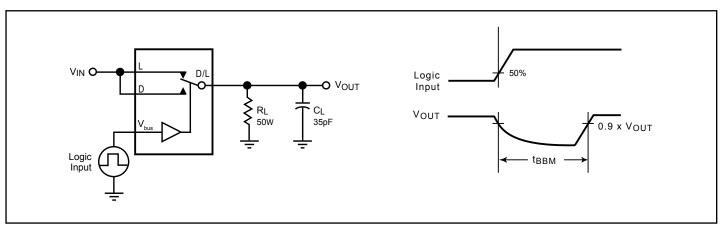
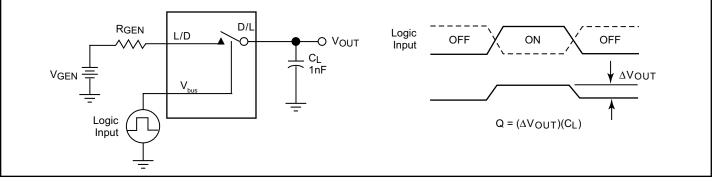


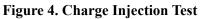
Figure 3. Break Before Make Interval Timing



A product Line of Diodes Incorporated

PI3USB223





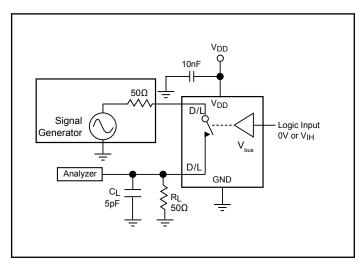


Figure 5. Off Isolation

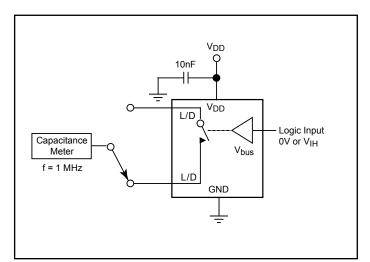


Figure 7. Channel Off Capacitance

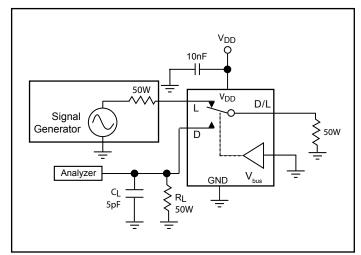
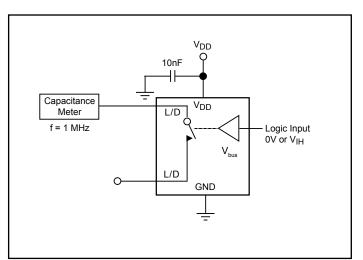
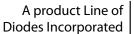


Figure 6. Crosstalk











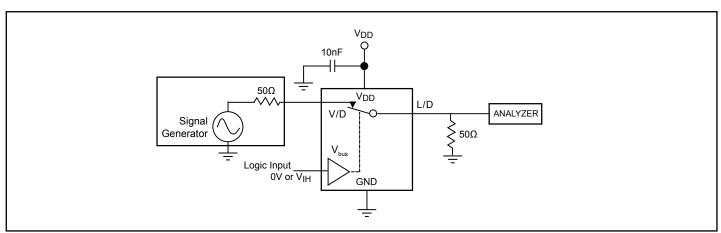


Figure 9. Bandwidth

Part Marking

ZM Package

Line above first chatacter denotes Lead-free and pin 1 indicator

RP YW

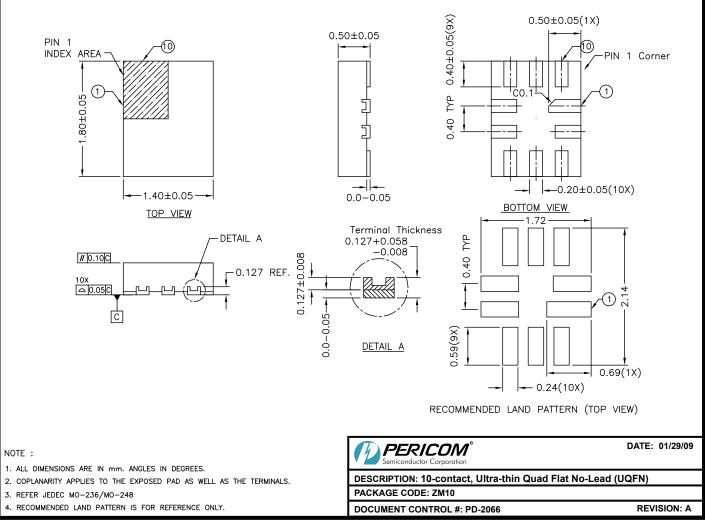
RP: PI3USB223ZME Y: Year W: Workweek





Packaging Mechanical





09-0072

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Description	Top Mark
PI3USB223ZMEX	ZM	10-contact, Ultra-thin Quad Flat No-Lead (UQFN)	RP

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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